

MPS6514

NPN General Purpose Amplifier

- This device is designed as a general purpose amplifier and switch.
- The useful dynamic range extends to 100mA as a switch and to 100MHz as an amplifier.



1. Emitter 2. Base 3. Collector

Absolute Maximum Ratings* T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	25	V
V _{CBO}	Collector-Base Voltage	40	V
V_{EBO}	Emitter-Base Voltage	4.0	V
I _C	Collector current - Continuous	200	mA
T _J , T _{stg}	Junction and Storage Temperature	-55 ~ +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

These ratings are based on a maximum junction temperature of 150 degrees C.
These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characte	eristics	ASS LEL			
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 0.5 \text{mA}, I_{\rm B} = 0$	25		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{C} = 10\mu A, I_{E} = 0$	40		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_C = 10\mu A, I_C = 0$	4.0		V
I _{CBO}	Collector Cutoff Current	$V_{CE} = 30V, I_{E} = 0$		50	nA
I _{CBO}	Collector Cutoff Current	$V_{CB} = 30V, I_{E} = 0, T = 100^{\circ}C$		1.0	μΑ
On Characte	eristics *				
h _{FE}	DC Current Gain	$I_C = 2.0 \text{mA}, V_{CE} = 10 \text{V}$ $I_C = 100 \text{mA}, V_{CE} = 10 \text{V}$	150 90	300	例
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 50mA, I _B = 5.0mA	199	0.5	V
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C _{obo}	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 100kHz$		3.5	pF

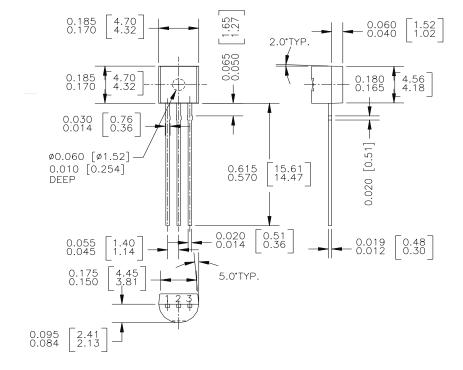
^{*} Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

Thermal Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

Package Dimensions

TO-92



Dimensions in Millimeters

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